

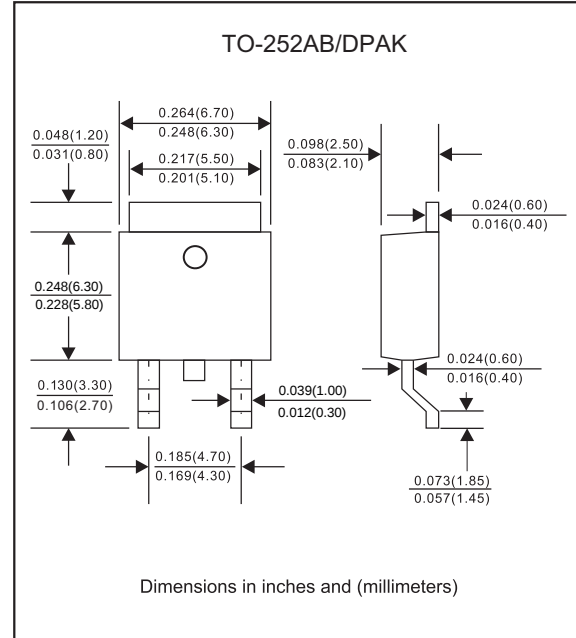
Features

- Batch process design, excellent power dissipation offers better reverse leakage current and thermal resistance.
- Low power loss, high efficiency.
- High current capability, low forward voltage drop.
- High surge capability.
- Guardring for overvoltage protection.
- Ultra high-speed switching.
- Silicon epitaxial planar chip, metal silicon junction.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228
- Compliant to Halogen-free

Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, TO-252AB/DPAK
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Mounting Position : Any

Package outline



Maximum ratings and Electrical Characteristics (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	See Fig.1	I_O			5.0	A
Forward surge current	8.3ms single half sine-wave (JEDEC methode)	I_{FSM}			90	A
Reverse current	$V_R = V_{RRM} \quad T_J = 25^{\circ}\text{C}$	I_R			0.1	mA
	$V_R = V_{RRM} \quad T_J = 125^{\circ}\text{C}$				20	
Diode junction capacitance	f=1MHz and applied 4V DC reverse voltage	C_J		600		pF
Thermal resistance (1)	Junction to Case	$R_{\theta JC}$		6		$^{\circ}\text{C/W}$
Storage temperature		T_{STG}	-55		+150	$^{\circ}\text{C}$

NOTE : (1) Device mounted on additional heatsink, (50mm x 50mm x 23mm Al heatsink).

SYMBOLS	V_{RRM}^{*1} (V)	V_{RMS}^{*2} (V)	V_R^{*3} (V)	V_F^{*4} (V)	Operating emperature T_J , ($^{\circ}\text{C}$)
MBR540YD	40	28	40	0.60	- 55 to +150
MBR545YD	45	31.5	45		
MBR560YD	60	42	60	0.70	
MBR5100YD	100	70	100	0.85	
MBR5150YD	150	105	150	0.90	
MBR5200YD	200	140	200	0.92	

*1 Repetitive peak reverse voltage

*2 RMS voltage

*3 Continuous reverse voltage

*4 Maximum forward voltage
IF = 5.0A, 25 $^{\circ}\text{C}$

Rating and characteristic curves (MBR540YD THRU MBR5200YD)

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

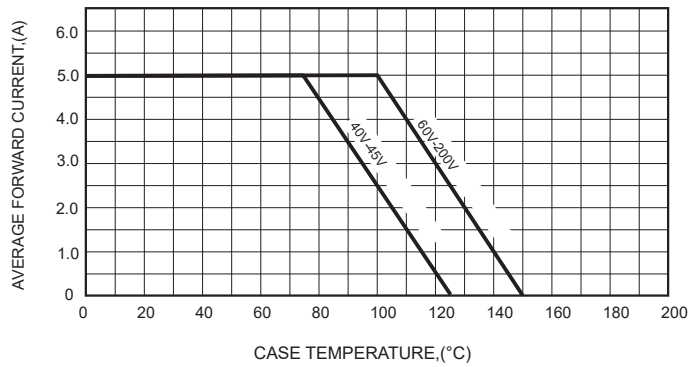


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

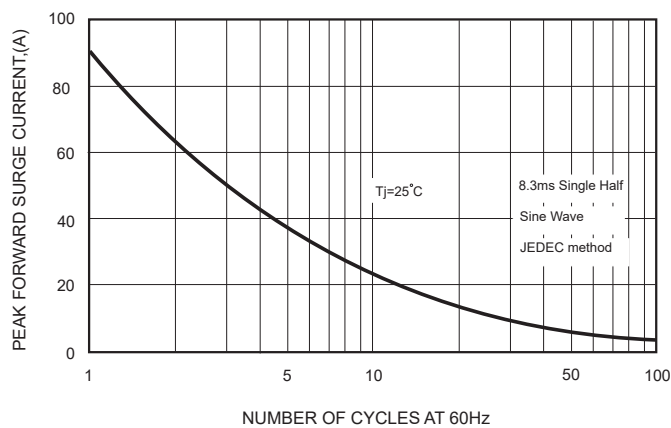


FIG.2-TYPICAL FORWARD CHARACTERISTICS

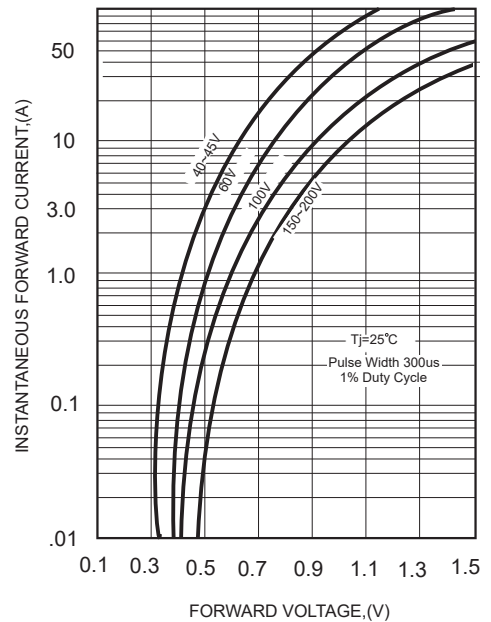
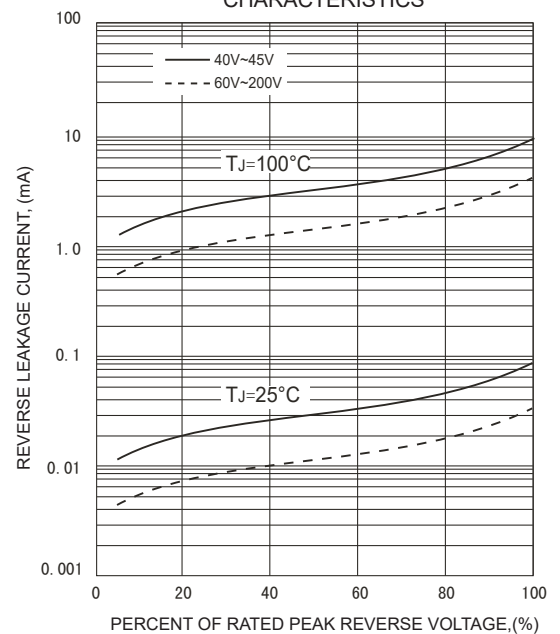
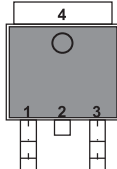
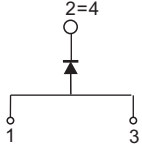


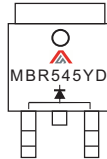
FIG.4 - TYPICAL REVERSE CHARACTERISTICS



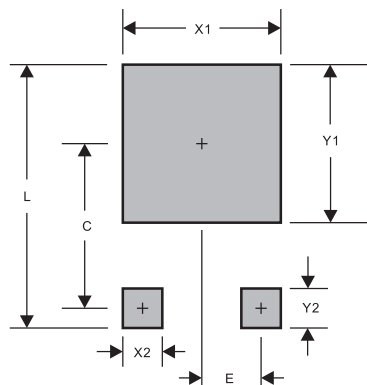
Pinning information

Pin	Simplified outline	Symbol
Pin1 anode Pin2=4 cathode Pin3 anode		

Marking

Type number	Marking code	Example
MBR540YD	MBR540YD	
MBR545YD	MBR545YD	
MBR560YD	MBR560YD	
MBR5100YD	MBR5100YD	
MBR5150YD	MBR5150YD	
MBR5200YD	MBR5200YD	

Suggested solder pad layout



PACKAGE	DPAK
C	0.272(6.90)
E	0.091(2.30)
L	0.457(11.60)
X1	0.276(7.00)
X2	0.059(1.50)
Y1	0.276(7.00)
Y2	0.098(2.50)

Dimensions in inches and (millimeters)